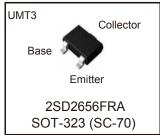
NPN 1A 30V Low Frequency Amplifier Transistors

Datasheet

AEC-Q101 Qualified

| Parameter | Value |
|----------------|-------|
| $V_{\sf CEO}$ | 30V |
| I _C | 1A |

Outline



Features

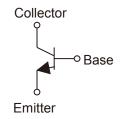
- 1) A Collecotr current is large. General Purpose.
- 2) Collector saturation voltage is low.

V_{CE(sat)} is Max. 350mV

At I_C =500mA, I_B =25mA

- 3) Complementary PNP Types : 2SB1694FRA
- 4) Lead Free/RoHS Compliant.

•Inner circuit



Applications

Driver circuit

Packaging specifications

| Part No. | Package | Package size (mm) | Taping code | Reel size (mm) | Tape width (mm) | Basic ordering unit (pcs) | Marking |
|------------|---------|-------------------------|----------------|-------------------|-----------------|---------------------------------|---------|
| 2SD2656FRA | UMT3 | 2021 | T106 | 180 | 8 | 3,000 | EU |

● Absolute maximum ratings (Ta = 25°C)

| Parameter | Symbol | Values | Unit |
|------------------------------|--------------------|-------------|------|
| Collector-base voltage | V_{CBO} | 30 | V |
| Collector-emitter voltage | V _{CEO} | 30 | V |
| Emitter-base voltage | V_{EBO} | 6 | V |
| Collector current | I _C | 1 | А |
| Collector current | I _{CP} *1 | 2 | А |
| Power dissipation | P_{D}^{*2} | 200 | mW |
| Junction temperature | T _j | 150 | °C |
| Range of storage temperature | T _{stg} | −55 to +150 | °C |

●Electrical characteristics (Ta = 25°C)

| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|-------------------|---|------|------|------|------|
| Collector-emitter breakdown voltage | BV _{CEO} | I _C = 1mA | 30 | ı | - | V |
| Collector-base breakdown voltage | BV _{CBO} | I _C = 10μA | 30 | ı | ı | V |
| Emitter-base breakdown voltage | BV _{EBO} | I _E = 10μA | 6 | ı | ı | V |
| Collector cut-off current | I _{CBO} | V _{CB} = 30V | ı | ı | 100 | nA |
| Emitter cut-off current | I _{EBO} | V _{EB} = 6V | - | - | 100 | nA |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 500 \text{mA}, I_B = 25 \text{mA}$ | ı | 140 | 350 | mV |
| DC current gain | h _{FE} | $V_{CE} = 2V, I_{C} = 100 \text{mA}^{*3}$ | 270 | ı | 680 | - |
| Transition frequency | f _T | $V_{CE} = 2V, I_{E} = -100 \text{mA}$ f=100MH _Z ^{*3} | ı | 400 | - | MHz |
| Output capacitance | C _{ob} | $V_{CB} = 10V$, $I_E = 0mA$ f = 1MHz | ı | 5 | - | pF |

^{*1} P_W=1ms Single pulse.

^{*2} Each terminal mounted on a reference footprint

^{*3} Pulsed

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

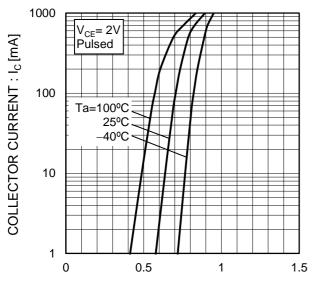
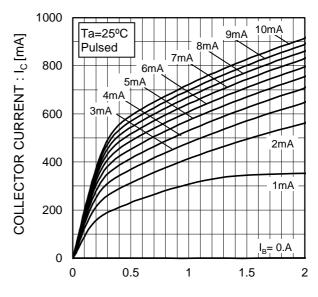


Fig.2 Typical Output Characteristics



BASE TO EMITTER VOLTAGE : $V_{BE}[V]$

COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current(I)

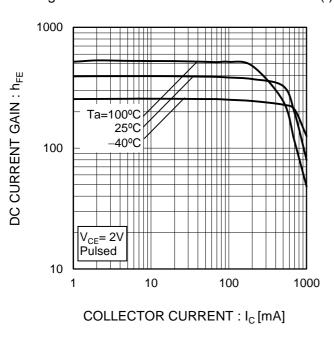
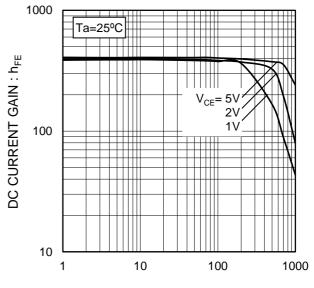
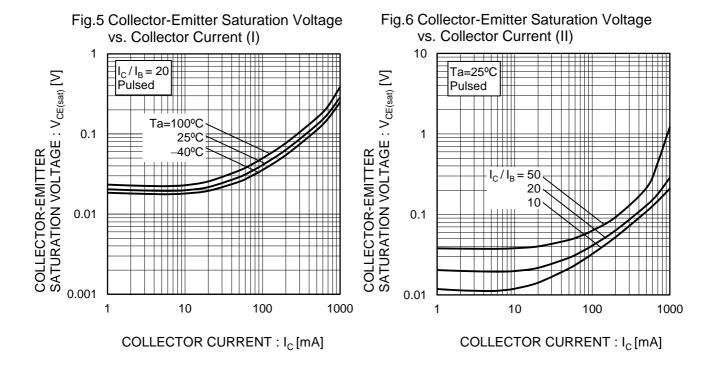


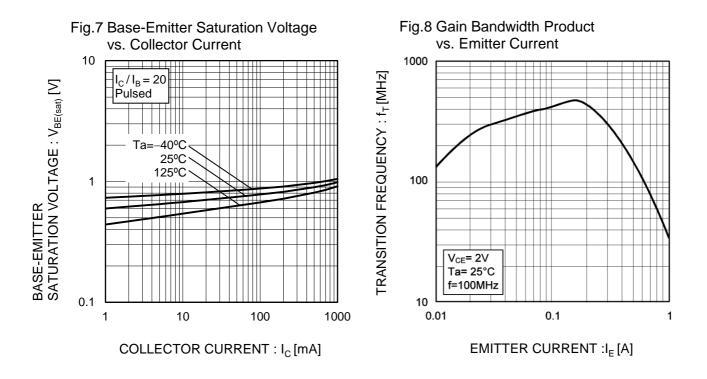
Fig.4 DC Current Gain vs. Collector Current(II)



COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)

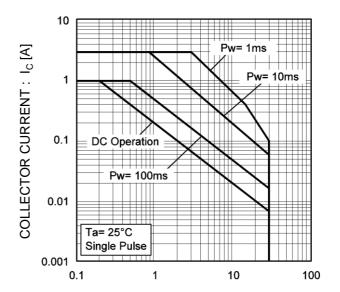




●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs. **Emitter-Base Voltage** Collector output capacitance vs. COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF] Collector-Base Voltage 100 C_{ib} 10 C_{ob} Ta= 25°C I_C=0A f=1MHz 0.01 0.1 1 10 100 COLLECTOR - BASE VOLTAGE : V_{CB} [V] EMITTER - BASE VOLTAGE : V_{EB} [V]

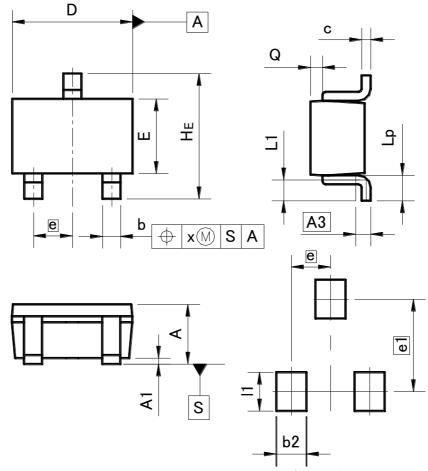
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}\left[V\right]$

●Dimensions (Unit:mm)

UMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

| DIM | MILIM | ETERS | INCHES | | |
|-------|-------|-------|--------|-------|--|
| DIIVI | MIN | MAX | MIN | MAX | |
| Α | 0.80 | 1.00 | 0.031 | 0.039 | |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 | |
| A3 | 0.: | 25 | 0.0 | 10 | |
| b | 0.15 | 0.30 | 0.006 | 0.012 | |
| С | 0.10 | 0.20 | 0.004 | 0.008 | |
| D | 1.90 | 2.10 | 0.075 | 0.083 | |
| E | 1.15 | 1.35 | 0.045 | 0.053 | |
| е | 0.65 | | 0.0 | 26 | |
| HE | 2.00 | 2.20 | 0.079 | 0.087 | |
| L1 | 0.20 | 0.50 | 0.008 | 0.020 | |
| Lp | 0.25 | 0.55 | 0.010 | 0.022 | |
| Q | 0.10 | 0.30 | 0.004 | 0.012 | |
| Х | | 0.10 | - | 0.004 | |

| DIM | MILIM | ETERS | INCHES | | |
|-----|-------|-------|--------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| b2 | _ | 0.50 | ı | 0.020 | |
| e1 | 1.55 | | 0.0 | 61 | |
| 11 | - | 0.65 | - | 0.026 | |

Dimension in mm / inches

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